

## T495A226M006AHE500

T495

MnO2 Tantalum

SMD, MnO2, Molded, Low ESR

http://www.p65warnings.ca.gov.

500 mOhms (100kHz 25C)

1.4 uA (5min 25°C)

387 mA (rms, 100kHz 25C), 348.3 mA (rms, 85C), 154.8 mA (rms, 125C)

MARNING: Cancer and reproductive harm -

1dd2e1b8-26dd-4d52-927c-6f9d519011aa

SMD Chip

Low ESR

Solder Coated

No

No

1

58.6 mg

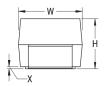
156 Weeks

T495, Tantalum, MnO2 Tantalum, 22 uF, 20%, 6.3 VDC, SMD, MnO2, Molded, Low ESR, 500 mOhms, 3216, Height Max = 1.8mm

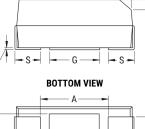
CATHODE (-) END VIEW

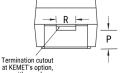


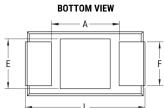
B



ANODE (+) END VIEW







at KEMET's option,	
either end	

Click here for the 3D model.

Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Н	1.6mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +0.2/-0.3mm
F	1.2mm +/-0.1mm
А	1.2mm MIN
В	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
Р	0.4mm REF
R	0.4mm REF
Х	0.1mm +/-0.1mm

т

Specifications	
Capacitance	22 uF
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
<b>Dissipation Factor</b>	6% 120Hz 25C
Failure Rate	N/A

Resistance

**Ripple Current** Leakage Current

**General Information** 

Series

Style

Dielectric

Description

Features

RoHS

Prop 65

SCIP Number

Termination

AEC-Q200

Component

Weight

MSL

Shelf Life

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

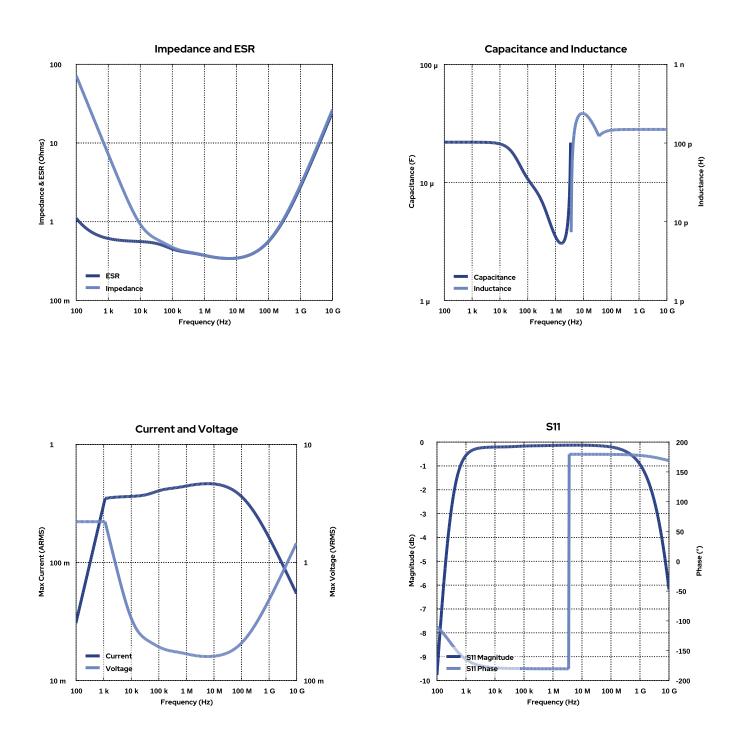
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any
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correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no
obligation or liability for the advice given or results obtained.



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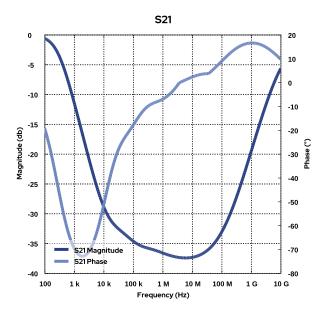
## Simulations

For the complete simulation environment please visit K-SIM.





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## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other
- harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.